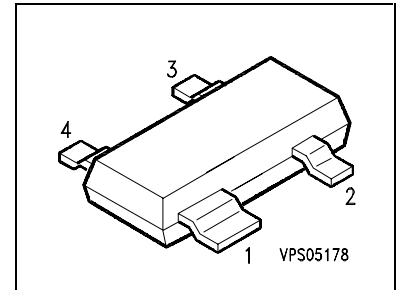


Silicon Bipolar MMIC-Amplifier

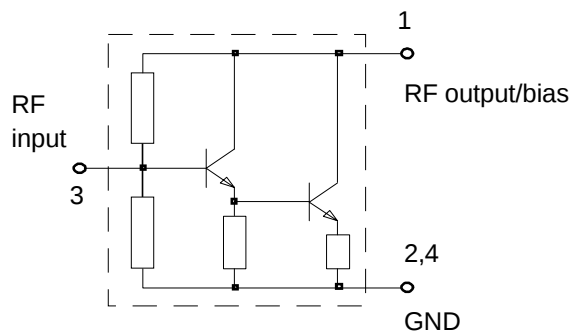
Preliminary Data

- Cascadable 50 Ω -Gain Block
- 11 dB typical Gain at 1.0 GHz
- 9 dBm typical P_{-1dB} at 1.0 GHz
- 3 dB-Bandwidth: DC to 2.0 GHz
- Plastic Package



Type	Marking	Ordering Code (8-mm taped)	Pin Configuration (circuit Diagram)	Package ¹⁾
BGA312	BMs	Q62702-G0042	see below	SOT143

Circuit Diagram



Maximum Ratings

Parameter	Symbol		Unit
Device current	I_D	60	mA
Total power dissipation, $T_s \leq 99^\circ\text{C}$ ²⁾	P_{tot}	250	mW
RF input power	P_{RFin}	10	dBm
Junction temperature	T_j	150	$^\circ\text{C}$
Ambient temperature range	T_A	-65...+150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-65...+150	$^\circ\text{C}$

Thermal Resistance

Junction-soldering point ²⁾	$R_{th JS}$	≤ 205	K/W
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1) For detailed information see page 4

2) T_s is measured on the RF output lead at the soldering point to the pcb.

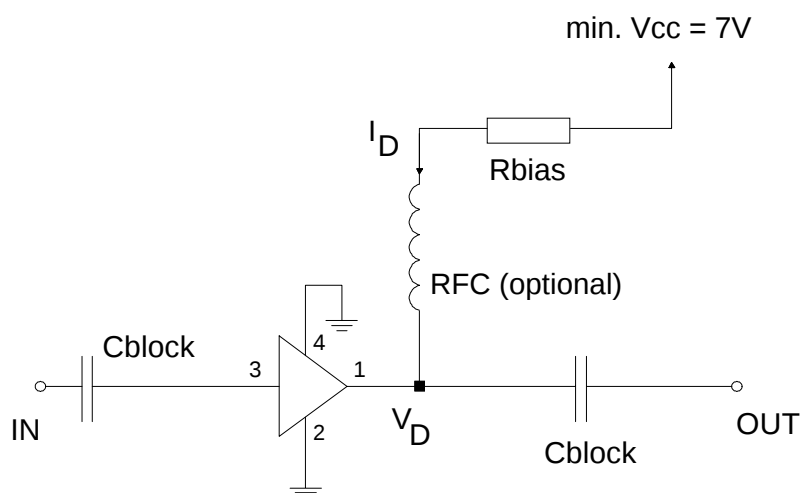
Electrical Characteristics

at $T_A = 25^\circ\text{C}$, unless otherwise specified.

$V_D = 4.7\text{ V}$, $Z_0 = 50\ \Omega$

Parameter	Symbol	Value			Unit
		min.	typ.	max.	
Insertion power gain $f = 0.1\text{ GHz}$ $f = 1.0\text{ GHz}$ $f = 1.8\text{ GHz}$	$ S_{21} ^2$		12 11 10		dB
Insertion power gain flatness $f = 0.1\text{ GHz to }0.6\text{ GHz}$	$\Delta S_{21} ^2$		± 0.6		dB
Noise figure $f = 0.1\text{ GHz}$ $f = 1.0\text{ GHz}$ $f = 2\text{ GHz}$	NF		5.5 6.0 7.0		dB
1dB Compression point output $f = 1\text{ GHz}$	$P_{-1\text{dB}}$		9		dBm
Return Loss $f = 0.1\text{ GHz to }2\text{ GHz}$ Input $f = 0.1\text{ GHz to }3\text{ GHz}$ Output	RL_{in} RL_{out}		20 14		dB

Typical Biasing Configuration



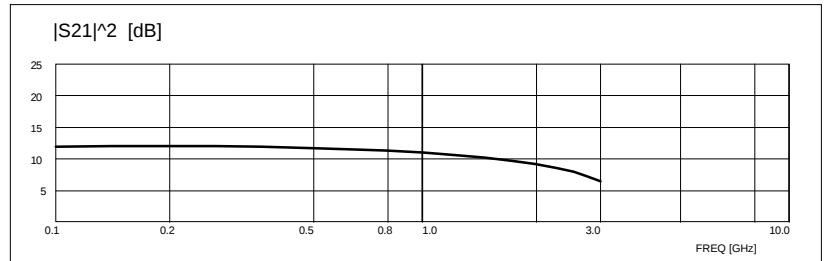
$$R_{\text{bias}} = \frac{V_{\text{CC}} - V_D}{I_D}$$

$$V_D = 4.7\text{ V}$$

Insertion power gain

vs. frequency

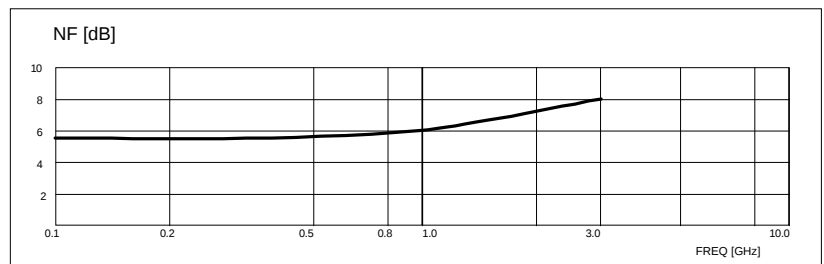
$V_D = 4.7 \text{ V}$, $I_D = 42 \text{ mA}$



Noise figure

vs. frequency

$V_D = 4.7 \text{ V}$, $I_D = 42 \text{ mA}$

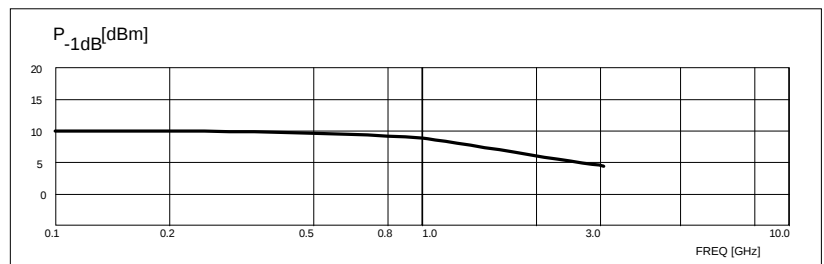


Output power

1-dB-Gain compression

vs. frequency

$V_D = 4.7 \text{ V}$, $I_D = 42 \text{ mA}$



Typical S-Parameters

at $T_A = 25 \text{ °C}$

f	S_{11}		S_{21}		S_{12}		S_{22}	
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
$V_D = 4.7 \text{ V}$, $Z_0 = 50 \text{ } \Omega$								
0.010	0.009	17.9	3.94	179.2	0.131	0.2	0.208	-0.5
0.100	0.012	43.5	3.95	174.4	0.131	1.7	0.207	-6.2
0.300	0.027	55.8	3.93	163.4	0.133	4.8	0.204	-19.1
0.500	0.039	52.5	3.89	152.2	0.136	7.8	0.201	-31.9
0.800	0.049	33.7	3.79	135.8	0.142	11.7	0.194	-51.3
1.000	0.046	22.2	3.69	124.9	0.149	13.8	0.191	-64.2
1.800	0.054	-135.4	3.13	84.1	0.181	16.6	0.183	-106.8
2.400	0.147	179.9	2.63	57.6	0.205	14.7	0.182	-124.9
3.000	0.240	152.1	2.19	35.7	0.225	11.6	0.184	-134.9